

**Preliminary**

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

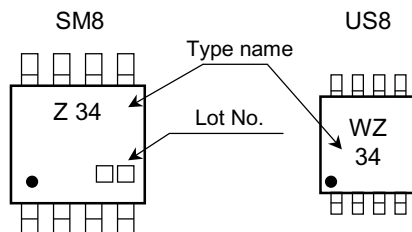
# TC7WZ34FU, TC7WZ34FK

Triple Non Inverter

## Features

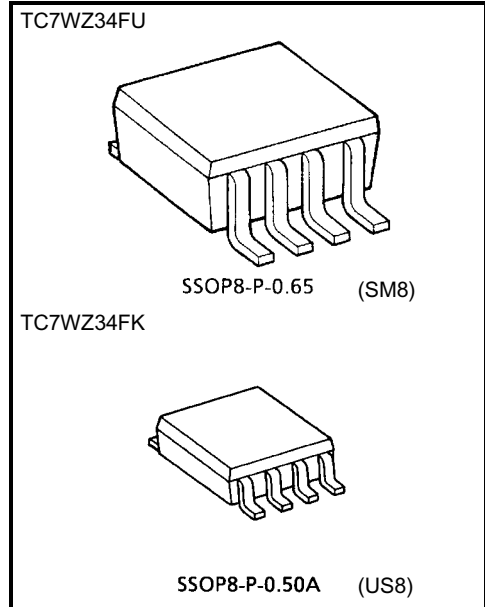
- High output drive:  $\pm 24$  mA (min) @  $V_{CC} = 3$  V
- Super high speed operation:  $t_{pd}$  2.4 ns (typ.) @  $V_{CC} = 5$  V, 50 pF
- Operation voltage range:  $V_{CC} (opr) = 1.65 \sim 5.5$  V
- Latch-up performance:  $\pm 500$  mA or more
- ESD performance:  $\pm 200$  V or more (EIAJ)  
 $\pm 2000$  V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V  $V_{CC}$ .

## Marking



## Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5~6	V
DC input voltage	$V_{IN}$	-0.5~6	V
DC output voltage	$V_{OUT}$	-0.5~6	V
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	-20	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 50$	mA
Power dissipation	$P_D$	300 (SM8) 200 (US8)	mW
Storage temperature	$T_{stg}$	-65~150	°C
Lead temperature (10s)	$T_L$	260	°C

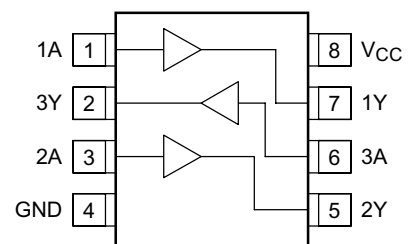


Weight

SSOP8-P-0.65 : 0.02 g (typ.)

SSOP8-P-0.50A : 0.01 g (typ.)

## Pin Assignment (top view)



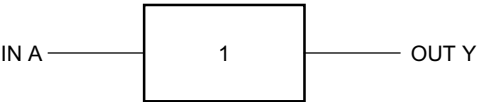
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Truth Table

A	Y
L	L
H	H

Logic Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	1.65~5.5	V
		1.5~5.5 (Note 1)	
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V
		0~V <sub>CC</sub> (Note 3)	
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	d <sub>t</sub> /d <sub>v</sub>	0~20 (V <sub>CC</sub> = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V)	ns/V
		0~10 (V <sub>CC</sub> = 3.3 V ± 0.3 V)	
		0~5 (V <sub>CC</sub> = 5.5 V ± 0.5 V)	

- Note 1: Data retention only
- Note 2: V<sub>CC</sub> = 0 V
- Note 3: High or low state

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• The information contained herein is subject to change without notice.

## Electrical Characteristics

## DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C				Ta = −40~85°C		Unit
					V <sub>CC</sub> (V)	Min	Typ.	Max	Min	Max	
Input voltage	High level	V <sub>IH</sub>	—	1.65~1.95	0.75 × V <sub>CC</sub>	—	—	0.75 × V <sub>CC</sub>	—	V	
				2.3~5.5	0.7 × V <sub>CC</sub>	—	—	0.7 × V <sub>CC</sub>	—		
	Low level	V <sub>IL</sub>	—	1.65~1.95	—	—	0.25 × V <sub>CC</sub>	—	0.25 × V <sub>CC</sub>		
				2.3~5.5	—	—	0.3 × V <sub>CC</sub>	—	0.3 × V <sub>CC</sub>		
Output voltage	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = −100 μA	1.65	1.55	1.65	—	1.55	—	V
					2.3	2.2	2.3	—	2.2	—	
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				I <sub>OH</sub> = −4 mA	1.65	1.29	1.52	—	1.29	—	
				I <sub>OH</sub> = −8 mA	2.3	1.9	2.14	—	1.9	—	
				I <sub>OH</sub> = −16 mA	3.0	2.4	2.75	—	2.4	—	
				I <sub>OH</sub> = −24 mA	3.0	2.3	2.62	—	2.3	—	
				I <sub>OH</sub> = −32 mA	4.5	3.8	4.13	—	3.8	—	
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.65	—	0	0.1	—	0.1	
					2.3	—	0	0.1	—	0.1	
					3.0	—	0	0.1		0.1	
					4.5	—	0	0.1	—	0.1	
				I <sub>OL</sub> = 4 mA	1.65	—	0.08	0.24	—	0.24	
				I <sub>OL</sub> = 8 mA	2.3	—	0.1	0.3		0.3	
				I <sub>OL</sub> = 16 mA	3.0	—	0.16	0.4		0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.24	0.55		0.55	
				I <sub>OL</sub> = 32 mA	4.5	—	0.25	0.55	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	0~5.5	—	—	±1	—	±10	μA	
Power off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	0.0	—	—	1	—	10	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND	1.65~5.5	—	—	1	—	10	μA	

AC Characteristics (unless otherwise specified, Input:  $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Ta = 25°C				Ta = -40~85°C		Unit
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 1 MΩ	1.8 ± 0.15	2.0	4.4	9.5	2.0	10.0	ns
			2.5 ± 0.2	1.0	3.0	5.2	1.0	5.8	
			3.3 ± 0.3	0.8	2.3	3.6	0.8	4.0	
			5.0 ± 0.5	0.5	1.8	2.9	0.5	3.2	
		C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 Ω	3.3 ± 0.3	1.2	3.0	4.6	1.2	5.1	
			5.0 ± 0.5	0.8	2.4	3.8	0.8	4.2	
Input capacitance	C <sub>IN</sub>	—	0~5.5	—	3.0	—	—	—	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note)	3.3	—	24	—	—	—	pF
			5.5	—	34	—	—	—	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

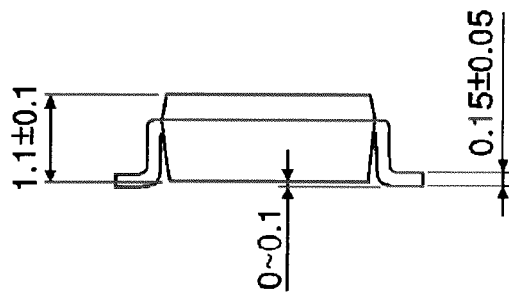
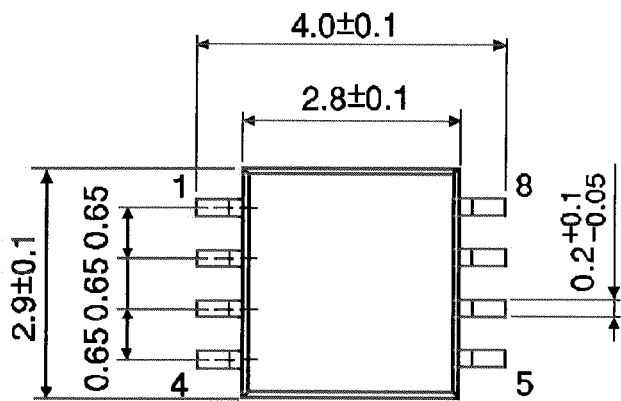
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$$

Package Dimensions

SSOP8-P-0.65

Unit : mm

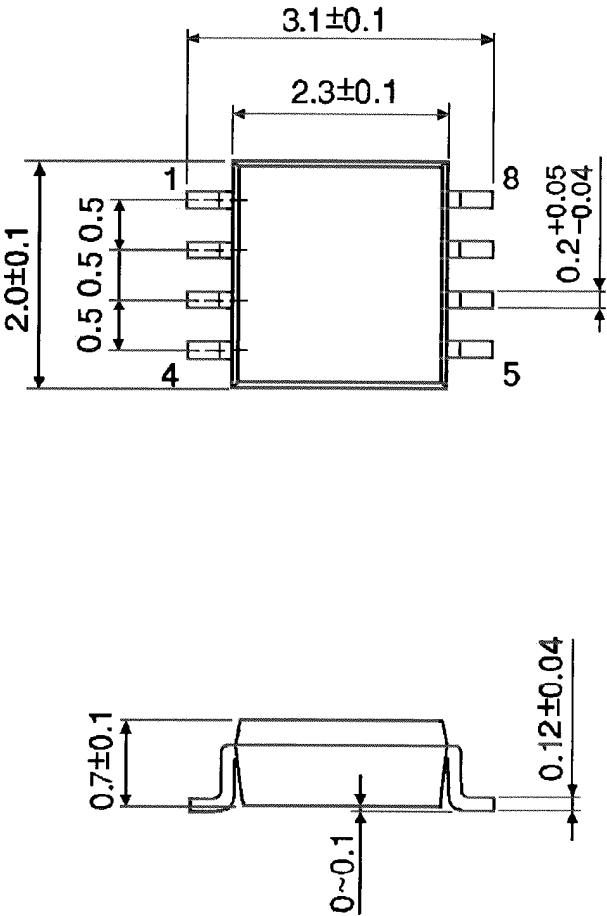


Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A

Unit : mm



Weight: 0.01 g (typ.)